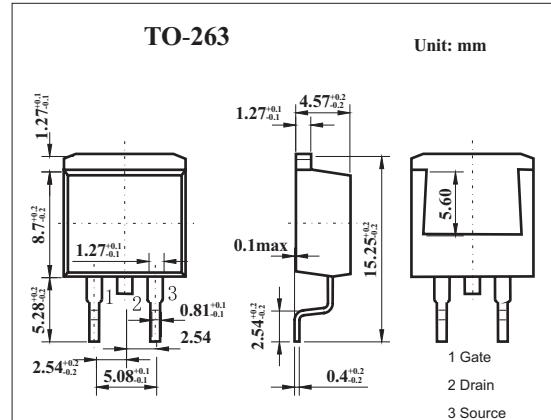


■ Features

- 4.5 V drive available
- Low on-state resistance
 $R_{DS(on)} = 12 \text{ m}\Omega \text{ MAX. } (V_{GS} = 10 \text{ V}, I_D = 18 \text{ A})$
- Low gate charge
 $Q_G = 30 \text{ nC TYP. } (I_D = 35 \text{ A}, V_{DD} = 16 \text{ V}, V_{GS} = 10 \text{ V})$
- Built-in gate protection diode
- Surface mount device available



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|--|------------|-------------|------------------|
| Drain to source voltage | V_{DSS} | 100 | V |
| Gate to source voltage | V_{GSS} | ± 20 | V |
| Drain current | I_D | ± 35 | A |
| | I_{Dp}^* | ± 140 | A |
| Power dissipation $T_a=25^\circ\text{C}$ | P_D | 1.5 | W |
| $T_c=25^\circ\text{C}$ | | 40 | |
| Channel temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

* $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Testconditions | Min | Typ | Max | Unit |
|-------------------------------------|---------------|---|-----|------|----------|------------------|
| Drain source surrender voltage | V_{DSS} | $I_D=1\text{mA}, V_{GS}=0$ | 100 | | | V |
| Drain cut-off current | I_{DSS} | $V_{DS}=20\text{V}, V_{GS}=0$ | | | 10 | μA |
| Gate leakage current | I_{GSS} | $V_{GS}=\pm 20\text{V}, V_{DS}=0$ | | | ± 10 | μA |
| Gat cutoff voltage | $V_{GS(off)}$ | $V_{DS}=10\text{V}, I_D=1\text{mA}$ | 1.0 | | 2.5 | V |
| Forward transfer admittance | $ Y_{fs} $ | $V_{DS}=10\text{V}, I_D=12\text{A}$ | 9.0 | | | S |
| Drain to source on-state resistance | $R_{DS(on)}$ | $V_{GS}=10\text{V}, I_D=18\text{A}$ | | 8.5 | 12 | $\text{m}\Omega$ |
| | | $V_{GS}=4.5\text{V}, I_D=18\text{A}$ | | 12 | 19 | $\text{m}\Omega$ |
| Input capacitance | C_{iss} | $V_{DS}=10\text{V}, V_{GS}=0, f=1\text{MHz}$ | | 1300 | | pF |
| Output capacitance | C_{oss} | | | 570 | | pF |
| Reverse transfer capacitance | C_{rss} | | | 300 | | pF |
| Turn-on delay time | t_{on} | $I_D=18\text{A}, V_{GS(on)}=10\text{V}, RG=10\Omega, V_{DD}=10\text{V}$ | | 70 | | ns |
| Rise time | t_r | | | 1220 | | ns |
| Turn-off delay time | t_{off} | | | 100 | | ns |
| Fall time | t_f | | | 180 | | ns |